BB150
VHF variable capacitance diode

Product specification
Supersedes data of December 1994
File under Discrete Semiconductors, SC01

1996 May 03
VHF variable capacitance diode BB150

FEATURES
- Excellent linearity
- Very small plastic SMD package
- C28: 2.5 pF; ratio: 16
- Low series resistance.

APPLICATIONS
- Electronic tuning in VHF television tuners, band B up to 460 MHz
- VCO.

DESCRIPTION
The BB150 is a double implanted variable capacitance diode, fabricated in planar technology, and encapsulated in the SOD323 very small SMD package.

The matched type, BB133 has the same specification.

LIMITING VALUES
In accordance with the Absolute Maximum Rating System (IEC 134).

<table>
<thead>
<tr>
<th>SYMBOL</th>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN.</th>
<th>TYP.</th>
<th>MAX.</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>V_R</td>
<td>continuous reverse voltage</td>
<td></td>
<td>–</td>
<td>30</td>
<td>V</td>
<td>V</td>
</tr>
<tr>
<td>I_F</td>
<td>continuous forward current</td>
<td></td>
<td>–</td>
<td>20</td>
<td>mA</td>
<td>mA</td>
</tr>
<tr>
<td>T_stg</td>
<td>storage temperature</td>
<td></td>
<td>–55</td>
<td>+150</td>
<td>°C</td>
<td>°C</td>
</tr>
<tr>
<td>T_j</td>
<td>operating junction temperature</td>
<td></td>
<td>–55</td>
<td>+125</td>
<td>°C</td>
<td>°C</td>
</tr>
</tbody>
</table>

ELECTRICAL CHARACTERISTICS
T_j = 25 °C; unless otherwise specified.

<table>
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<tr>
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<th>TYP.</th>
<th>MAX.</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>I_R</td>
<td>reverse current</td>
<td>V_R = 30 V; see Fig.3</td>
<td>–</td>
<td>–</td>
<td>10</td>
<td>nA</td>
</tr>
<tr>
<td></td>
<td></td>
<td>V_R = 30 V; T_j = 85 °C; see Fig.3</td>
<td>–</td>
<td>–</td>
<td>200</td>
<td>nA</td>
</tr>
<tr>
<td>r_s</td>
<td>diode series resistance</td>
<td>f = 100 MHz; note 1</td>
<td>–</td>
<td>–</td>
<td>0.9</td>
<td>Ω</td>
</tr>
<tr>
<td>C_d</td>
<td>diode capacitance</td>
<td>V_R = 0.5 V; f = 1 MHz; see Figs 2 and 4</td>
<td>38</td>
<td>–</td>
<td>46</td>
<td>pF</td>
</tr>
<tr>
<td></td>
<td></td>
<td>V_R = 28 V; f = 1 MHz; see Figs 2 and 4</td>
<td>2.2</td>
<td>–</td>
<td>2.6</td>
<td>pF</td>
</tr>
<tr>
<td>C_d(0.5V) / C_d(28V)</td>
<td>capacitance ratio</td>
<td>f = 1 MHz</td>
<td>14</td>
<td>–</td>
<td>21</td>
<td></td>
</tr>
</tbody>
</table>

Note
1. V_R is the value at which C_d = 30 pF.
Fig. 2  Diode capacitance as a function of reverse voltage; typical values.

Fig. 3  Reverse current as a function of junction temperature; maximum values.

Fig. 4  Temperature coefficient of diode capacitance as a function of reverse voltage; typical values.
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PACKAGE OUTLINE

DEFINITIONS

Data sheet status
- Objective specification: This data sheet contains target or goal specifications for product development.
- Preliminary specification: This data sheet contains preliminary data; supplementary data may be published later.
- Product specification: This data sheet contains final product specifications.

Limiting values
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information
Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS
These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.